NSR0140P2T5G

Schottky Barrier Diode

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage 0.28 V (Typ) @ I_F = 1.0 mA
- Low Reverse Current
- Lead–Free Plating
- This is a Pb–Free Device

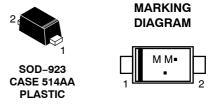


ON Semiconductor®

http://onsemi.com

40 V SCHOTTKY BARRIER DIODE





M = Specific Device Code*

(Character is rotated 270° clockwise)

M = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NSR0140P2T5G	SOD-923 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RM}	40	V
Continuous Reverse Voltage (DC)	V _R	30	V
Continuous Forward Current (DC)	١ _F	70	mA
Non-Repetitive Peak Forward Surge Current	I _{FSM}	500	mA
ESD Rating: Class 1C per Human Body Mode Class A per Machine Model	1		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

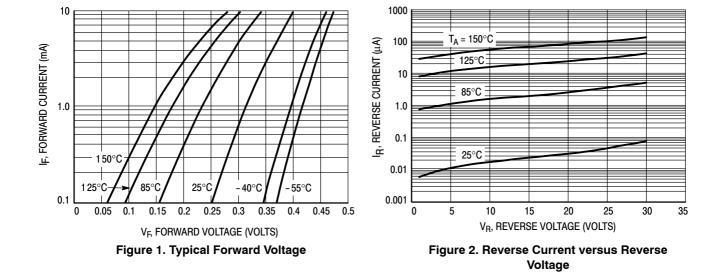
Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR–5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	100 1.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	1000	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +125	°C

1. FR-5 Minimum Pad.

NSR0140P2T5G

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \ \mu A)$	V _{(BR)R}	30	-	_	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	C _T	-	2.0	2.5	pF
Reverse Leakage (V _R = 30 V)	I _R	-	300	500	nA
Forward Voltage (I _F = 1.0 mA)	V _F	_	0.28	0.35	V

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)



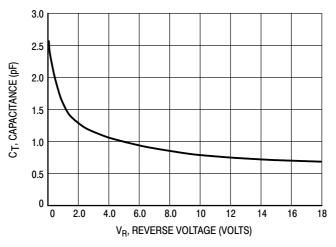
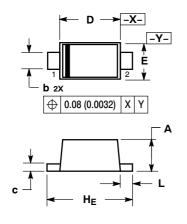


Figure 3. Typical Capacitance

NSR0140P2T5G

PACKAGE DIMENSIONS

SOD-923 CASE 514AA-01 ISSUE D

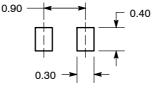


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD
- THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.34	0.39	0.43	0.013	0.015	0.017
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
Е	0.55	0.60	0.65	0.022	0.024	0.026
Η _E	0.95	1.00	1.05	0.037	0.039	0.041
L	0.05	0.10	0.15	0.002	0.004	0.006

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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